

 Database: EPODOC

[EPODOC: SS 1] glove and prevention

Results in EPODOC **321**

[SS 2] ss1 and tunnel

Results in EPODOC **1**

[SS 3] ..li



1/1 © EPODOC / EPO

PN - [JP2007317920](#) A 20071206

PR - JP20060146479 20060526

AP - JP20060146479 20060526

DT - 1

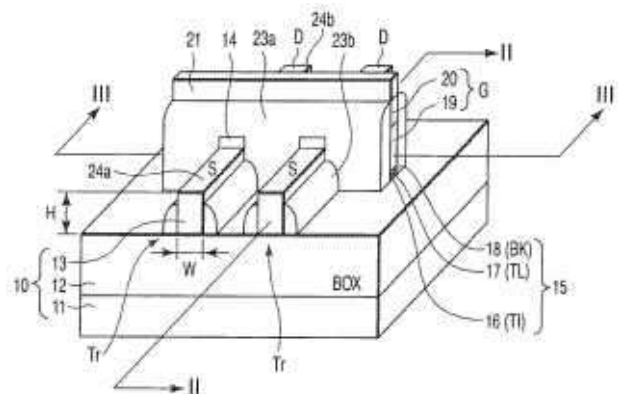
CCI - [H01L21/84](#) ; [H01L29/7923](#) ;
[H01L27/115](#) ; [H01L27/11568](#) ;
[H01L27/1203](#) ; [H01L29/0847](#)

CCA - [H01L29/785](#)

FI - H01L27/10&434; H01L27/115;
H01L27/11519; H01L27/11521;
H01L27/11565; H01L27/11568;
H01L29/78&371

FT

- 5F083/EP03; 5F083/EP14;
5F083/EP15; 5F083/EP17;
5F083/EP18; 5F083/ER03;
5F083/ER30; 5F083/GA09;
5F083/GA29; 5F083/HA02;
5F083/JA03; 5F083/JA04;
5F083/JA35; 5F083/JA36;
5F083/JA39; 5F083/JA40;
5F083/LA21; 5F083/PR09;
5F083/PR40; 5F083/ZA21;
5F101/BA03; 5F101/BA12;
5F101/BA42; 5F101/BA45;
5F101/BB08; 5F101/BC02;
5F101/BD30; 5F101/BE02;
5F101/BE05; 5F101/BE07;
5F101/BF05



- PA - TOSHIBA CORP
- TI - SEMICONDUCTOR MEMORY
DEVICE AND ITS MANUFACTURING
METHOD
- AB - PROBLEM TO BE SOLVED: To
provide a semiconductor
memory device which can be
miniaturized, and to provide its
manufacturing method.
- SOLUTION: The semiconductor
memory device comprises a
semiconductor substrate 11, an
insulating film 12 formed on the
semiconductor substrate, a fin-
shaped semiconductor layer 13
formed on the insulating film
and having a first and a second
side **SS1**, SS2 mutually facing, a
gate electrode G formed to stride
over the first and the second side
of the semiconductor layer, a
trap layer TL provided between
the gate electrode and the first
side of the semiconductor layer,
a **tunnel** gate insulating film TI
provided between the trap layer
and the first side of the
semiconductor layer, a control
gate insulating film CI provided
between the trap layer and the
gate electrode, a channel region
formed in the semiconductor
layer under the gate electrode;
and a source region S and a
drain region D formed in the
semiconductor layer to
sandwich the channel region,
including a metal, and
respectively having a Schottky
junction between channel region.
- COPYRIGHT: (C)2008,JPO&INPIT

[SS 3] tunnel and carpien

Results in EPODOC 0

EPODOC: term 'CARPIAN' not found in index 'BI'. WARNING(1)

[SS 4] carpal and tunnel

Results in EPODOC 764

[SS 5] glove and ss4

Results in EPODOC 0

[SS 6] ss4 and prevention

Results in EPODOC 2

[SS 7] ..li



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PN - [CN205022607U](#) U 20160210
PR - CN20152765340U 20150930
AP - CN20152765340U 20150930
DT - I
PA - CHINA RAILWAY NO 3 ENG GROUP; CHINA RAILWAY NO 3 GROUP CO LTD TRANSP
ENGINEERING BRANCH
TI - **SS4** changes wrong device of locomotive **prevention** 93 valves conversion
AB - The utility model belongs to the technical field of **SS4** changes locomotive equipment,
specifically a **SS4** changes wrong device of locomotive **prevention** 93 valves
conversion. The problem of **prevention** **SS4** change 93 valves in locomotive conversions
mistake is solved, a **SS4** changes wrong device of locomotive **prevention** 93 valves
conversion, including stretching into the nylon stick in 93 valve transition mast
consents and fixing the iron box in 93 valve transition mast consents top, 93 the drill
way department of valve transition mast consent is equipped with round -meshed
fender lid and check ring, the iron box bottom is equipped with the opening that can let
the nylon stick pass through, be equipped with in the iron box and have the micro -gap
switch who normally opens with the normal close function, micro -gap switch fixes
directly over the nylon stick, nylon stick top is equipped with the position sleeve with
iron box fixed connection.

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PN - [JP2000296200](#) A 20001024
PNFP - JP3577235B B2 20041013
PR - JP19990050460 19990226; JP19990034437 19990212
AP - JP19990050460 19990226
DT - I
FI - A63F5/04&512D; A63F5/04&516E; A63F5/04&516F; A63F5/04&516G
FT - 2C082/AA02; 2C082/AA03; 2C082/AA05; 2C082/AA06; 2C082/AB03; 2C082/AB05;
2C082/AB12; 2C082/AB25; 2C082/BA02; 2C082/BA03; 2C082/BA22; 2C082/BA32;
2C082/BA37; 2C082/BB02; 2C082/BB03; 2C082/BB13; 2C082/BB15; 2C082/BB23;

2C082/BB32; 2C082/BB33; 2C082/BB35; 2C082/BB46; 2C082/BB58; 2C082/BB83;
2C082/BB94; 2C082/BB96; 2C082/CA02; 2C082/CA03; 2C082/CA07; 2C082/CA23;
2C082/CA24; 2C082/CA25; 2C082/CA27; 2C082/CA29; 2C082/CB04; 2C082/CB14;
2C082/CB23; 2C082/CB32; 2C082/CB33; 2C082/CB42; 2C082/CB47; 2C082/CB50;
2C082/CC01; 2C082/CC12; 2C082/CC24; 2C082/CC28; 2C082/CC37; 2C082/CC46;
2C082/CD03; 2C082/CD06; 2C082/CD31; 2C082/CD41; 2C082/CD49; 2C082/CD55;
2C082/CE12; 2C082/CE13; 2C082/CE15; 2C082/DA02; 2C082/DA13; 2C082/DA19;
2C082/DA51; 2C082/DB07; 2C082/DB14; 2C082/DB17; 2C082/DB25; 2C082/EA26

PA - (A)
SANKYO CO

TI - (A)
SLOT MACHINE

AB - (A)
PROBLEM TO BE SOLVED: To provide a slot machine capable of preventing settings of winning rate from being changed into settings of higher winning rate by use of illegal noises such as electric waves. SOLUTION: In this slot machine, in which settings of winning rate are automatically renewed by initialization of a RAM to provide new settings corresponding to a dispense rate of approximately 100%, an illegal act **prevention** means which can detect illegal noises from the outside is provided, and when the RAM storing a set value of winning rate is initialized (**SS4**), the **prevention** means determines whether or not it has been initialized by use of illegal noises (**SS5**); when it has been initialized by illegal noises, settings of winning rate in the RAM are renewed again to provide settings 1 (dispense rate of 95.2%) for the lowest winning rate (**SS6**), and this is reported by a reporting means (**SS8**).